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37 CFR 1.116  
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CFR 1.125(a)

matter from

Thank you!

Claim

Yamaguchi

DE

Claim

*Ed Schuster*

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ily subject

isaya) or

Claim 8 is amended by explicitly entering former claims 5 and 6.

Claim 22 is cancelled.

Claims 23 and 24 take the wording from claim 22 and the values of claims 23 and

24.

A Terminal Disclaimer concerning pending application 09/847,658, filed May 2, 2001, is submitted herewith.

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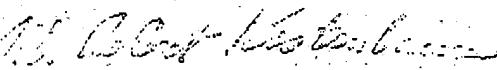
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Wherefore, further consideration and allowance of the claims is respectfully  
requested.

A three-month extension of time in which to respond to the outstanding Office  
Action is hereby requested. A PTO-2038 authorizing credit card payment for the amount  
of \$950 is enclosed for the prescribed Large Entity three-month extension fee, \$110 for  
the terminal disclaimer fee and \$330 for the Notice of Appeal fee. Any other fees due by  
virtue of this filing or this application should be charged to Deposit Account 11-0665.  
Any refunds in connection with this filing should be credited to Deposit Account 11-  
0665. A duplicate of this page is enclosed for this purpose.

Respectfully submitted,



M. Robert Kestenbaum  
Reg. No. 20,430  
11011 Bermuda Dunes NE  
Albuquerque, NM USA 87111  
Telephone (505) 323-0771  
Facsimile (505) 323-0865

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872-9306.



M. Robert Kestenbaum

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In the claims:

1. (Previously presented) A projection objective for microlithography having a lens arrangement comprising:

a first lens group having positive power;

a second lens group having negative power;

a third lens group having positive power;

a fourth lens group consisting of lenses with spherical surfaces, said fourth lens group having negative power;

a fifth lens group having positive power; and

a sixth lens group having positive power;

wherein a lens at the end of said second lens group, or a lens at the beginning of said third lens group, has an aspheric surface.

2. (Original) The projection objective according to claim 1, wherein said lens at the end of said second lens group is the last lens of the second lens group.

3. (Original) The projection objective according to claim 1, wherein said lens at the beginning of said third lens group is the first lens of said third lens.

4. (Original) The projection objective according to claim 1, wherein said lens arrangement has only one lens having an aspheric surface.

5. (Canceled)

6. (Canceled)

7. (Previously presented) The projection objective according to claim 5, wherein said lens arrangement has a first lens group having positive power, a second lens group having negative power, a third lens group having negative power, a fourth lens group consisting

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of lenses with spherical surfaces, said fourth lens group having negative power, and a fifth and sixth lens group respectively having positive power, wherein said first lens group has a lens having an aspheric surface.

8. (Currently amended) The projection objective according to claim 6 A projection objective having a lens arrangement having at least a first waist of a pencil of rays, wherein said lens arrangement comprises at least one of the following:

a lens having an aspheric surface arranged before said first waist,

a lens having an aspheric surface arranged after said first waist, and

lenses having aspheric surfaces arranged before and after said first waist,

wherein at least two spherical lenses are arranged between said lenses having aspheric surfaces,

wherein a lens having an aspheric surface is arranged in said second lens group before said waist.

9. (Original) The projection objective according to claim 7, wherein said third lens group has a lens having an aspheric surface.

10. (Canceled)

11. (Original) The projection objective according to claim 1, wherein said sixth lens group has a first lens having an aspheric surface.

12. (Original) The projection objective according to claim 1, wherein a last lens of said third lens group has an aspheric surface.

13. (Original) The projection objective according to claim 1, wherein said lens arrangement does not exceed a maximum lens diameter of 280 mm.

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14. (Original) The projection objective according to claim 13, wherein said lens arrangement does not exceed a maximum lens diameter of 250 mm.

15. (Original) The projection objective according to claim 1, having an object side and an image side, wherein said lens arrangement has on said image side a numerical aperture of at least 0.75.

16. (Original) The projection objective according to claim 15, wherein said lens arrangement has on said image side a numerical aperture of 0.8.

17. (Original) The projection objective according to claim 1, wherein said lens arrangement comprises at least two different materials.

18. (Original) The projection objective according to claim 17, wherein said different materials comprise quartz glass and a fluoride or two fluorides.

19. (Original) The projection objective according to claim 8, further comprising an aperture stop wherein at least a last two positive lenses before said aperture stop are comprised of  $\text{CaF}_2$ .

20. (Original) The projection objective according to claim 1, wherein said lens arrangement comprises a positive lens comprised of  $\text{CaF}_2$ , followed by a negative lens of quartz glass, for formation of an achromat.

21. (Original) The projection objective according to claim 1, wherein said sixth lens group comprises a lens of  $\text{CaF}_2$ .

22. (Canceled)

23. (Currently Amended) ~~The refractive microlithographic projection objective according to claim 19, A refractive microlithographic projection objective, having a lens~~

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arrangement comprising at least one lens with an aspheric lens surface, wherein all aspheric lens surfaces have a said vertex radius (R) is of at least 350-1,000 mm.

24. (Currently Amended) The refractive microlithographic objective according to claim 22, A refractive microlithographic projection objective, having a lens arrangement comprising at least one lens with an aspheric lens surface, wherein all aspheric lens surfaces have wherein said a vertex radius (R) is greater than 1,000 mm.

25. (Original) The projection objective for microlithography according to claim 1, wherein the diameter said lens having an aspheric surface is smaller than 90% of the maximum diameter of said lens arrangement.

26. (Original) The projection objective according to claim 25, wherein the diameter of said lens having an aspheric surface is smaller than 80% of the maximum diameter of said lens arrangement.

27. (Original) A projection exposure device for microlithography, comprising a projection objective according to claim 1.

28. (Original) A projection exposure device for microlithography, comprising an excimer laser light source emitting radiation of wavelength shorter than 250 nm, and a projection objective according to claim 19.

29. (Original) The projection objective comprising a lens arrangement according to claim 1, wherein said lens arrangement has a high numerical aperture on an objective output side, and all lenses of said lens arrangement have sine values of all angles of incidence of radiation striking a respective lens that are always smaller than the numerical aperture of said lens arrangement.

30. (Original) The projection objective according to claim 29, wherein said numerical

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aperture is in the region of 0.85.

31. (Original) The projection objective comprising a lens arrangement according to claim 1, wherein the maximum diameter of lenses of said third lens group is at least 10% smaller than the maximum diameter of lenses of said fifth lens group.

32. (Original) The projection objective comprising a lens arrangement according to claim 1, wherein at least one aspheric lens surface is acted on with an angle loading of at least  $\sin i = 0.75$ .

33. (Original) A process for the production of microstructured components, comprising:  
exposing a substrate provided with a photosensitive layer with ultraviolet light by means of a mask and a projection exposure device with a lens arrangement according to claim 1, and,

if necessary after development of said photosensitive layer, structuring said substrate corresponding to a pattern contained on said mask.

34. (Previously presented) A projection objective for microlithography having a lens arrangement comprising:

- a first lens group having positive power;
- a second lens group having negative power;
- a third lens group having positive power;
- a fourth lens group having negative power;
- a fifth lens group having positive power; and
- a sixth lens group having positive power;

wherein a lens at the end of said second lens group, or a lens at the beginning of said third lens group, has an aspheric surface, and

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wherein said lens at the end of said second lens group is the last lens of the second lens group.

35. (Previously presented) The projection objective according to claim 34, wherein said lens at the beginning of said third lens group is the first lens of said third group.

36. (Previously presented) The projection objective according to claim 34, wherein said lens arrangement has only one lens having an aspheric surface.

37. (Previously presented) A projection objective for microlithography having a lens arrangement comprising:

a first lens group having positive power;

a second lens group having negative power;

a third lens group having positive power;

a fourth lens group having negative power;

a fifth lens group having positive power; and

a sixth lens group having positive power;

wherein a lens at the end of said second lens group, or a lens at the beginning of said third lens group, has an aspheric surface, and

wherein a last lens of said third lens group has an aspheric surface.

38. (Previously presented) A projection objective for microlithography having a lens arrangement comprising:

a first lens group having positive power;

a second lens group having negative power;

a third lens group having positive power;

a fourth lens group having negative power;

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a fifth lens group having positive power; and

a sixth lens group having positive power;

wherein a lens at the end of said second lens group, or a lens at the beginning of said third lens group, has an aspheric surface, and

wherein said lens arrangement does not exceed a maximum lens diameter of 280 mm.

39. (Previously presented) The projection objective according to claim 38, wherein said lens arrangement does not exceed a maximum lens diameter of 250 mm.

40. (Previously presented) A projection objective for microlithography having a lens arrangement comprising:

a first lens group having positive power;

a second lens group having negative power;

a third lens group having positive power;

a fourth lens group having negative power;

a fifth lens group having positive power; and

a sixth lens group having positive power;

wherein a lens at the end of said second lens group, or a lens at the beginning of said third lens group, has an aspheric surface, and

the projection objective having an object side and an image side, wherein said lens arrangement has on said image side a numerical aperture of 0.8.

41. (Previously presented) A projection objective for microlithography having a lens arrangement comprising:

a first lens group having positive power;

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a second lens group having negative power;

a third lens group having positive power;

a fourth lens group having negative power;

a fifth lens group having positive power; and

a sixth lens group having positive power;

wherein a lens at the end of said second lens group, or a lens at the beginning of said third lens group, has an aspheric surface, and

wherein said sixth lens group comprises a lens of  $\text{CaF}_2$ .

42. (Previously presented) The projection objective according to claim 41, wherein said numerical aperture is in the region of 0.85.

43. (Previously presented) A projection objective for microlithography having a lens arrangement comprising:

a first lens group having positive power;

a second lens group having negative power;

a third lens group having positive power;

a fourth lens group having negative power;

a fifth lens group having positive power; and

a sixth lens group having positive power;

wherein a lens at the end of said second lens group, or a lens at the beginning of said third lens group, has an aspheric surface, and

wherein the maximum diameter of lenses of said third lens group is at least 10% smaller than the maximum diameter of lenses of said fifth lens group.

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44. ( Previously presented) A projection objective for microlithography having a lens arrangement comprising:

- a first lens group having positive power;
- a second lens group having negative power;
- a third lens group having positive power;
- a fourth lens group having negative power;
- a fifth lens group having positive power; and
- a sixth lens group having positive power;

wherein a lens at the end of said second lens group, or a lens at the beginning of said third lens group, has an aspheric surface, and

wherein at least one aspheric lens surface is acted on with an angle loading of at least  $\sin i = 0.75$ .

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## Projection Objection Objective for Microlithography

### Cross References to Related Applications

This application is a continuation application of PCT/EP99/10233, which is pending.

German Applications DE 198 55 108A, DE 198 55 157A, and DE 198 55 158A, in which the Applicant participated, are incorporated herein by reference.

### Statement Regarding Federal Sponsored Research or Development – Not Applicable.

### Reference to a Microfiche Appendix – Not Applicable.

### Background of the Invention

#### Technical Field

The invention relates to a projection objective with a lens arrangement, which can be divided into six lens groups. The first, third, fifth and sixth lens groups have positive power and the second and fourth lens groups respectively have negative power. The division of the lens system into lens groups is described in more detail hereinafter, based on the direction of propagation of the radiation.

The first lens group is positive and ends with a lens of positive power. A bulge is formed by the first lens group; it is unimportant if negative lenses are also arranged in the bulge.

The second lens group is of negative total power. This second lens group has as its first lens a lens having a concave lens surface toward the image. This second lens group substantially describes a waist. Here, also it is not of substantial importance if a few positive lenses are included in the second lens group, as long as the waist is maintained.

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The third lens group begins with a lens having positive power and a convex lens surface on the image side, and which can be a meniscus. If a thick meniscus lens is provided as the first lens, the separation of the lens groups can be considered to be within the lens.

The fourth lens group is of negative power. This fourth lens group begins with a lens of negative power, followed by several lenses having negative power. A waist is formed by this lens group. It is unimportant if lenses having positive power are also contained within this lens group, as long as these influence the course of the beam over only a short distance and thus the waisted shape of the fourth lens group is maintained.

The fifth lens group has positive power overall. The first lens of this fifth lens group has a convex lens surface on the image side. A bulge is formed by the fifth lens group.

After the lens of maximum diameter (the bulge), there follow at least an additional two positive lenses in the fifth lens group, further negative lenses also being permitted.

The sixth lens group is likewise positive in its total power. The first lens of the sixth lens group is negative and has on the image side a concave lens surface. This first lens of the sixth lens group has a considerably smaller diameter in comparison with the maximum diameter of the bulge.

#### Background Art

Such projection objectives are in particular used in microlithography. They are known, for example, from the German Applications DE 198 55 108A, DE 198 55 157A, and DE 198 55 158A, in which the Applicant participated, and from the state of the art cited therein. These documents are incorporated herein by reference.

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These projection objectives are usually constructed from purely spherical lenses, since the production and testing technology is advantageous for spheres.

Projection objectives are known from German Application DE 198 18 444 A1 which have lenses having aspheric surfaces in at least the fourth or fifth lens group. An increase of the numerical aperture and of the image quality can be attained by means of the aspheric surfaces. The projection objectives shown have a length from the mask plane to the image plane of 1,200 mm to 1,500 mm. A considerable use of material is associated with this length. High production costs are entailed by this use of material, since because of the required high image quality only high quality materials can be used. Aspheric lenses up to a diameter of about 300-mm are required, the provision of which is particularly expensive. It is not at all clear in the technical world whether aspheric lenses with such large lens diameters can be provided in the required quality. "Aspheric surfaces" are understood to include all surfaces which are not spherical and which are rotationally symmetrical. Rotationally symmetrical splines can also be considered as aspheric lens surfaces.

#### Summary of the Invention

The invention has as its object to provide a projection objective which has as few lenses as possible, with reduced use of material, the aspheric lens surfaces used being as few and as small as possible, with the lowest possible asphericity. A high aperture projection objective of short structure is to be cost-efficiently provided in this way.

The object of the invention is attained in particular by a projection objective for microlithography having a lens arrangement comprising a first lens group having positive power;

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a second lens group having negative power; a third lens group having positive power; a fourth lens group having negative power; a fifth lens group having positive power; and a sixth lens group having positive power; wherein a lens at the end of the second lens group, particularly the last lens of the second lens group, or a lens at the beginning of the third lens group, particularly the first lens of the third lens group, has an aspheric surface. In addition, the object of the invention is attained by a projection objective having a lens arrangement having at least a first waist of a pencil of rays, wherein the lens arrangement comprises at least one of the following: a lens having an aspheric surface arranged before the first waist, a lens having an aspheric surface arranged after the first waist, and lenses having aspheric surfaces arranged before and after the first waist.

In a projection objective with a lens arrangement, by the measure of providing, in the forward half of this lens arrangement, at least one lens provided with an aspheric lens surface, the possibility was realized of furnishing a projection objective of compact construction and having a high image quality.

In the division of this lens arrangement into six lens groups: a first lens group having a positive power, a second lens group a negative power, a third lens group a positive power, a fourth lens group a negative power, and a fifth and sixth lens group respectively a positive power, a preferred position of the aspheric surface is at the end of the second lens group. It is then arranged, in particular, on the last lens of the second lens group or at the beginning of the third lens group, and indeed preferably on the first lens of the third lens group. A correction of image errors in the region between the image field zone and the image field edge is possible by means

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of this aspheric lens surface. In particular, the image errors of higher order, which become evident on considering sagittal sections, can be corrected. Since these image errors apparent in sagittal section are particularly difficult to correct, this is a particularly valuable contribution. In an advantageous embodiment, only one lens has an aspheric surface. This has a positive effect on the production costs, since it is the production of highly accurate aspheric surfaces that requires considerable technological effort, which entails increased costs. It was only with the use of exactly one aspheric lens that it was possible to provide a very compact objective, in which case the additional costs for the aspheric lens are not important, since considerable cost savings were connected with the reduction of the required material and of the surfaces to be processed and tested.

By the measure of providing a lens arrangement that has at least a first waist, an aspheric surface before and an aspheric surface after the waist, a lens arrangement is produced which makes possible a high numerical aperture with high image quality, particularly for the DUV region. In particular, it is possible by the use of these aspheric surfaces to furnish a projection objective of short structure and high image quality. Objectives used in microlithography generally have a high material density over their whole length, so that the reduction of the length is connected with a considerable saving of material. Since only very high-grade materials can be used for projection objectives, particularly for microlithography, the required use of material has a severe effect on the production costs.

The aspheric surface arranged before the first waist can be arranged at the end of the first lens group or at the beginning of the second lens group. Furthermore, it has been found to be

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advantageous to arrange an aspheric surface, arranged after the first waist, on the last lens of the second lens group or on the first lens of the third lens group.

The aspheric surface provided before the first waist in particular makes possible a targeted correction of coma in the region of the image field zone. This aspheric lens surface has only a slight effect on the skew spherical aberration in tangential section and in sagittal section. In contrast to this, the skew sagittal aberration, particularly in the region between the image field zone and image field edge, can be corrected by the aspheric lens surface after the waist.

The provision of a second aspheric lens surface is thus a worthwhile measure, in order to counter at high numerical aperture a reduction of image quality due to coma.

In a few cases of application, particularly with very high numerical aperture, it has been found to be favorable to provide a projection objective wherein the third lens group has a lens having an aspheric surface, and, in particular, the last lens of the third lens group has an aspheric surface.

It has been found to be advantageous to provide a first lens in the sixth lens group with an aspheric surface for a further correction of coma, especially in the region of the image field edge. For this aspheric lens surface, the first lens of the sixth lens group has been found to be a particularly well suited position.

Furthermore, the numerical aperture can be increased, at constant image quality, by the provision of a further aspheric surface on the last lens of the third lens group.

It is an advantage of the invention to provide a refractive microlithographic projection objective, wherein all aspheric lens surfaces have a vertex radius (R) of at least 300-mm. Thus

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the aspheric surfaces are provided on long radii, since the production and testing is easier for lens surfaces with long radii. These surfaces are easily accessible to processing equipment because of their low curvature. In particular, surfaces with long radii are accessible with Cartesian coordinates for tactile measurement processes.

It has been found to be advantageous to use at least two different materials for achromatization, for projection objectives designed for an illumination wavelength of less than 200 nm, because of the stronger dispersion of the lenses, even with the use of narrow-band light sources. In particular, fluorides, especially  $\text{CaF}_2$ , are known as suitable materials, besides quartz glass.

It has been found to be advantageous to provide at least two lenses of  $\text{CaF}_2$ , which are arranged before an aperture stop in the fifth lens group, for the correction of color transverse errors.

It has been found to be advantageous for the further correction of color errors to integrate an achromat after the aperture stop by means of a positive  $\text{CaF}_2$  lens and a following negative quartz lens. This arrangement has a favorable effect on the correction of the spherical portions. In particular, longitudinal color errors can be corrected by the lenses after the aperture stop.

A reduction of the longitudinal error already results in general from the shortening of the length of the projection objective. Thus a good achromatization with a reduced use of  $\text{CaF}_2$  lenses can be attained with the objective according to the invention.

#### Brief Description of the Drawings

The invention is described in more detail hereinafter with the aid of preferred

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embodiments, in which:

Fig. 1 shows a schematic illustration of a projection exposure device;

Fig. 2 shows a lens section through a first lens arrangement of a projection objective with an aspheric lens surface;

Fig. 3 shows a lens section through a second lens arrangement, which has two aspheric lens surfaces;

Fig. 4 shows a lens section through a third lens arrangement, which has three aspheric lens surfaces;

Figs. 5a-5g illustrate tangential transverse aberrations;

Figs. 6a-6g illustrate sagittal transverse aberrations;

Figs. 7a-7f illustrate groove errors of the third lens arrangement with the aid of sections;

Fig. 8 shows a lens section through a fourth lens arrangement, which has three aspheric surfaces;

Fig. 9 shows a lens section through a fifth lens arrangement, which has four aspheric surfaces;

Fig. 10 shows a lens section through a sixth lens arrangement, which has four aspheric surfaces.

#### Detailed Description of Preferred Embodiments

The principle of the construction of a projection exposure device is first described with the aid of Fig. 1. The projection exposure device 1 has an illuminating device 3 and a projection objective 5. The projection objective includes a lens arrangement 19 with an aperture stop AP, an optical axis 7 being defined by the lens arrangement 19. A mask 9 is arranged between the illuminating device 3 and the projection objective 5, and is supported in the beam path by means

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of a mask holder 11. Such masks 9 used in microlithography have a micrometer to nanometer structure, which is reduced by means of the projection objective 5 by a factor of up to 10, particularly a factor of four, and is imaged on an image plane 13. A substrate positioned by a substrate holder 17 or a wafer 15 is supported in the image plane 13. The minimum structures which are still resolvable depend on the wavelength  $\lambda$  of the light used for illumination, and also on the numerical aperture of the projection objective 5, the maximum attainable resolution of the projection exposure device 1 increasing with decreasing wavelength of the illuminating device 3 and with increasing numerical aperture of the projection objective 5.

The projection objective 5 contains, according to the invention, at least one aspheric surface to provide a high resolution.

Various embodiments of lens arrangements 19 are shown in Figs. 2-4 and 8-10.

These projection objectives 5 designed for more stringent requirements for image quality and for resolution, and in particular their lens arrangement 19, are described in more detail hereinafter. The data of the individual lenses L101-130, L201-230, L301-330, L401-429, L501-529, L601-629, can be found in detail in the associated tables. All the lens arrangements 19 have at least one aspheric lens surface 27.

These aspheric surfaces are described by the equation:

$$P(h) = \frac{\delta \cdot h \cdot h}{1 + \sqrt{1 - (1 - EX) \cdot \delta \cdot \delta \cdot h \cdot h}} + C_1 h^4 + \dots + C_n h^{2n+2} \quad \delta = 1/R$$

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in which  $P$  is the arrow height as a function of the radius  $h$  (height to the optical axis 7) with the aspheric constants  $C_1$  through  $C_n$  given in the Tables.  $R$  is the vertex angle given in the Tables.

The lens arrangement 19 shown in Fig. 2 has 29 lenses L101-L129 and a plane parallel plate L-130. This lens arrangement 19 can be divided into six lens groups, which are denoted by LG1 for the first lens group through LG6 for the sixth lens group. The first, fifth and sixth lens groups have positive refractive power, while the second lens group LG2 and the fourth lens group LG4, by which a first waist 23 and a second waist 25 are formed, have negative refractive power. This lens arrangement 19 is designed for the wavelength  $\lambda = 193.3$  nm which is produced by a KrF excimer laser, and has an aspheric lens surface 27. A structure width of  $0.10 \mu\text{m}$  is resolvable with this lens arrangement 19 at a numerical aperture of 0.75. On the object side, the light transmitted by the lens arrangement propagates in the form of a spherical wavefront. In the objective, the greatest deviation from the ideal wavefront, also denoted by the RMS factor, is  $10.4 \text{ m}\lambda$  with respect to the wavelength  $\lambda = 193.3$  nm. The image field diagonal is 28 mm. The constructional length from mask plane to object plane is only 1,000 mm, and the maximum diameter of a lens is 235 mm.

In this embodiment, this aspheric lens surface 27 is arranged on the side of the lens L110 remote from the illumination device.

The projection objective having the previously mentioned good performance data could

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for the first time be furnished with the use of this aspheric lens surface 27. This aspheric lens surface 27 serves to correct image errors and also to reduce the required constructional length, with image quality remaining constant. In particular, image errors of higher order in the region between the image zone and image field edge are corrected here by this aspheric surface 27. This correction brings about, in particular, an increase in the image quality in the sagittal direction.

The dispersion of the available lens materials increases with shorter wavelengths. Consequently, increased chromatic image errors arise in projection objectives for short wavelengths such as 193 nm or 157 nm. The usual embodiment for 193 nm therefore has quartz glass as the flint and CaF<sub>2</sub> as the crown, as lens materials for achromatization.

With an overall minimum use of the problematic CaF<sub>2</sub>, care has to be taken in that a CaF<sub>2</sub> lens L114 in the third lens group LG3 places an increased requirement on the homogeneity of the material, since it is arranged far from the aperture stop AP. For this purpose, however, it has a moderate diameter, which substantially improves the availability of CaF<sub>2</sub> with an increased requirement.

For the correction of color transverse error, three CaF<sub>2</sub> lenses L119, L120, L121 are arranged in the fifth lens group LG5, before the aperture stop AP. An achromat 37, consisting of a convex CaF<sub>2</sub> lens L122 and a following meniscus lens L123 of quartz glass are arranged directly behind the aperture stop AP. These CaF<sub>2</sub> lenses can be of lower quality than the CaF<sub>2</sub> lens L114, since quality deviations in the middle region can easily be simultaneously corrected for all image field regions (by lens rotation during adjustment).

A further CaF<sub>2</sub> lens L129 is arranged in the sixth lens group. It is possible by means of

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this lens of  $\text{CaF}_2$  to reduce the effects of lens heating and refractive index changes due to irradiation, named compaction.

The individual data for the lenses L101-L130 can be found in Table 1. The optically utilized diameter of all the  $\text{CaF}_2$  lenses is less than 235 mm. Since the availability of  $\text{CaF}_2$  is furthermore limited in dependence on the diameter required, the required diameter of the  $\text{CaF}_2$  lenses used is of central importance.

A lens arrangement 19 designed for the wavelength  $\lambda = 248 \text{ nm}$  is shown in section in Fig. 3. This lens arrangement 19 has two aspheric lens surfaces 27, 29. The first aspheric lens surface 27 is arranged on the image side on the lens L210. It can also be provided to arrange this second aspheric lens surface 27 on the side of the lens L211 facing toward the illumination device. The two lenses L210 and L211 are predetermined for the reception of the aspheric lens surface 27. Provision can also be made to provide a meniscus lens having an aspheric lens surface instead of the lenses L210 and L211. The second aspheric lens surface 29 is arranged in the end region of the first lens group, on the side of the lens L205 remote from the illumination device 3. It can also be provided to arrange this aspheric lens surface 29 on the lens L206 following thereafter in the beginning of the second lens group.

A particularly great effect is obtained when the aspherics 27, 29 are arranged on lens surfaces at which the incident rays include a large angle with the respective surface normals. In this case the large variation of the angle of incidence is important. In Fig. 10, the value of  $\sin i$  at the aspheric lens surface 31 reaches a value of up to 0.82. Because of this, the two mutually facing lens surfaces of lenses L210, L211 in this embodiment have a greater effect on the course

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of the rays in comparison with the respective other lens surfaces of the corresponding lenses L210, L211.

With a length of 1,000 mm and a maximum lens diameter of 237.3 mm, this lens arrangement has a numerical aperture of 0.75 at a wavelength of 193.3 nm. The image field diagonal is 27.21 mm. A structure width of 0.15  $\mu\text{m}$  is resolvable. The greatest deviation from the ideal wavefront is 13.0  $\text{m}\lambda$ . The exact lens data with which these performance data were attained can be found in Table 2.

A further embodiment of a lens arrangement 19 for the wavelength 248.38 nm is shown in Fig. 4. This lens arrangement 19 has three lenses L305, L310, L328 which respectively have an aspheric lens surface 27, 29, 31. The aspheric lens surfaces 27, 29 have been left at the positions given by Fig. 3. The coma of middle order can be adjusted for the image field zone by means of the aspheric lens surface 27. The repercussions on sections in the tangential direction and in the sagittal direction are then small.

The additional, third aspheric lens surface 31 is arranged on the mask side on the lens L328. The aspheric lens surface 31 supports coma correction toward the image field edge.

By means of these three aspheric lens surfaces 27, 29, 31, there are attained, at a wavelength of 248.38 nm and at a length of only 1,000 mm and a maximum lens diameter of 247.2 mm, the further increased numerical aperture of 0.77 and a structure width of 0.14  $\mu\text{m}$  which can be well resolved in the whole image field. The maximum deviation from the ideal wavefront is 12.0  $\text{m}\lambda$ .

In order to keep the diameter of the lenses in LG5 small, and in order for a Petzval sum

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which, advantageously for the system, should be kept nearly zero, the three lenses L312, L313, L314 in the third lens group LG3 are enlarged. The thicknesses, and thus the diameters, of other lenses, particularly the lenses of the first group LG1, have been reduced in order to furnish the required axial constructional space for these three lenses L312-L314. This is an excellent way to arrange very large image fields and apertures in a restricted constructional space.

The high image quality which is attained by this lens arrangement can be seen in Figs. 5a-5g, 6a-6g and 7a-7f.

Figs. 5a-5g give the meridional transverse aberration DYM for the image height Y' (in mm). All show an outstanding course up to the highest DW'.

Figs. 6a-6g give the sagittal transverse aberrations DZS as a function of the half aperture angle DW' for the same image heights (mm).

Figs. 7a-7f give the groove error DYS, which is nearly zero throughout.

The exact lens data can be found in Table 3; the aspheric lens surfaces 27, 29, 31 have a considerable participation in the high image quality which can be ensured.

A further lens arrangement for the wavelength  $\lambda = 248.38$  nm is shown in Fig. 8. With a length of only 1,000 mm, this lens arrangement 19 has, with only three aspheric lens surfaces 27, 29, 31, a numerical aperture of 0.8; a structure width of  $0.13 \mu\text{m}$  is well resolvable in the whole image field, whose diagonal is 27.21 mm. The maximum lens diameter is 255 mm and occurs in the region of the fifth lens group LG5. The lens diameter is unusually small for the numerical aperture of 0.8 at an image field having a 27.21 mm diagonal. All three aspheric lens surfaces 27, 29, 31 are in the front lens groups LG1-LG3 of the lens arrangement 19. The deviation from

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the ideal wavefront is only  $9.2 \text{ m}\lambda$  in this lens arrangement.

The exact lens data of this lens arrangement can be found in Table 4.

A further increase of the numerical aperture, from 0.8 to 0.85, could be attained by the provision of a further, fourth aspheric 33 on the side of the lens L513 remote from the illuminating device. This high numerical aperture, from which there results an acceptance angle of  $116.4^\circ$ , as against an angle of  $88.8^\circ$  with a numerical aperture of 0.70, is unparalleled for the image field with diagonal 27.21 mm. The well resolvable structure width is  $0.12 \mu\text{m}$ , and the maximum deviation from the ideal wavefront is only  $7.0 \text{ m}\lambda$ . Such a lens arrangement 19 is shown in Fig. 9, and the exact lens data can be found in Table 5.

In comparison with the preceding embodiments of Figs. 1-3 and with the cited DE 198 18 444 A, the last two lenses are united into one lens in this lens arrangement 19. By this measure, in addition to the savings in lens production, a lens mounting can be saved in the end region, so that constructional space is created for auxiliary devices, especially for a focus sensor.

A lens arrangement 19 designed for the wavelength  $\lambda = 157.63 \text{ nm}$  is shown in Fig. 10. The image field which can be illuminated with this lens arrangement has been reduced to  $6 \times 13$  mm, with an image field diagonal of 14.3 mm, and is adapted for the stitching process.

With a length of only 579.5 mm and a maximum diameter of 167 mm, and with four aspheric lens surfaces 27, 29, 31, 33, a numerical aperture of 0.85 and a well resolvable structure width of  $0.07 \mu\text{m}$  were attained. The deviation from the ideal wavefront is  $9.5 \text{ m}\lambda$  at the wavelength  $\lambda = 157.63 \text{ nm}$ .

The absorption of quartz lenses is quite high because of the short wavelength, so that

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rccourse was increasingly had to CaF<sub>2</sub> as the lens material. Single quartz glass lenses are provided in the region of the waists 23, 25, i.e., in the second and fourth lens groups LG2 and LG4. These quartz glass lenses are to have the highest possible transmission. A further lens of quartz glass, in the form of a meniscus lens L625, is provided in the lens group LG5 to form an achromat. Furthermore in lens group LG6, the lens L628 having an aspheric lens surface is of quartz glass. The aspheric surface 33 is thus constituted of the material which is easier to process.

The color longitudinal error of this lens arrangement 19 is thus very small, even at this very high numerical aperture.

The embodiments hereinabove show that good performance data can be attained without aspheric surfaces (27, 29, 31, 33) having large diameters, especially in the fifth lens group. The small aspheric lens surfaces utilized can easily be made and tested.

These lens arrangements 19 illustrated in the embodiments show solely the design space set out by the claims. Of course, the features according to the claims and their combinations, put in concrete terms with the aid of the embodiments, can be combined with each other.

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Table 1  
page 1

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Lenses	Radii	Thicknesses	Glasses	1/2 x Lens Diameter
	infinity	17.2885		
L101	-143.20731	6.0000	SiO2	62.436
	599.77254	7.6370	He	62.972
L102	-3259.25331	17.8056	SiO2	70.359
	-215.68976	.7500	He	72.015
L103	6352.48088	21.0301	SiO2	74.027
	-222.97760	.7500	He	79.278
L104	375.05253	22.1160	SiO2	80.492
	-496.09705	.7500	SiO2	83.813
L105	191.46102	26.2629	He	83.813
	-1207.32624	.7500	SiO2	81.276
L106	180.94629	15.5881	He	80.032
	100.48826	25.3787	SiO2	72.339
L107	-3031.88082	6.0000	He	62.801
	122.14071	23.8879	SiO2	62.147
L108	-295.91467	9.3246	He	58.984
	-187.69352	.7500	SiO2	59.196
L109	-199.96963	6.0000	He	59.874
	184.23629	33.9482	SiO2	59.882
L110	-112.01095	6.0000	He	62.911
	-684.63799 A	12.5079	SiO2	64.128
L111	-225.51622	18.8059	He	75.868
	-137.30628	.7500	SiO2	78.258
L112	5312.93388	38.3345	He	81.928
	-178.79712	.7500	SiO2	99.979
L113	344.71979	39.8511	He	101.920
	-397.29552	.7500	SiO2	111.294
L114	165.51327	39.6778	He	111.237
	7755.09540	.7500	CAF2	101.552
L115	195.28524	23.8921	He	99.535
	119.89272	32.2730	SiO2	87.267
L116	-452.93918	6.0000	He	72.012
	287.33119	20.7820	SiO2	70.763
L117	-218.82578	6.0000	He	66.677
	166.44429	40.5757	SiO2	66.150
L118	-103.80788	6.4932	He	66.003
	5916.88891	13.3336	SiO2	66.694
L119	-344.93456	19.8584	He	80.525
	-165.11801	.7500	CAF2	82.790
L120	-11871.72431	38.5095	He	66.174
	-174.34079	.7500	CAF2	100.670
L121	586.98079	31.6815	He	102.666
	-414.20537	.7500	CAF2	111.739
infinity	infinity	3.6849	He	112.097
	stop	.0000	He	111.399
L122	284.84742	1.2586	He	111.399
	-414.78783	45.7670	CAF2	114.801
L123	-234.72451	17.9539	He	114.410
		14.5097	SiO2	113.062

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Table 1

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L124	-593.08647	14.7730	He	114.454
	-323.13567	42.1874	SiO <sub>2</sub>	114.235
L125	-229.08128	.7500	He	117.505
	180.27184	31.4105	SiO <sub>2</sub>	105.659
	652.02194	.7500	He	103.698
L126	143.20049	28.2444	SiO <sub>2</sub>	91.476
	383.51531	14.7177	He	88.206
L127	-2122.47818	14.1140	SiO <sub>2</sub>	85.843
	312.60012	1.3119	He	74.816
L128	111.92162	46.5147	SiO <sub>2</sub>	66.708
	53.69539	2.2604	He	40.084
L129	51.14657	27.3776	CAF <sub>2</sub>	39.074
	492.53747	3.7815	He	32.621
	infinity	3.0000	SiO <sub>2</sub>	29.508
	infinity	12.0000		27.848
	infinity			14.021

Aspheric Constants:Coefficients of the aspheric surface  $\eta$ :[where  $\eta$  is 21]

EX = 0.0000

C1 = 0.61839643  $\cdot 10^{-4}$ C2 = -0.11347761  $\cdot 10^{-11}$ C3 = 0.32783915  $\cdot 10^{-18}$ C4 = -0.22000186  $\cdot 10^{-20}$

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Table 2

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Lenses	Radii	Thicknesses	Glasses	$\frac{1}{2} \times$ Lens Diameter
--------	-------	-------------	---------	------------------------------------

	infinity	16.6148		
L201	-140.92104	.70000	SiO2	60.752
	-4944.48962	4.5190		61.267
L202	-985.90856	16.4036	SiO2	67.230
	-191.79393	.7500		68.409
L203	18376.81346	16.5880	SiO2	70.127
	-262.28779	.7500		73.993
L204	417.82018	.21.1310	SiO2	74.959
	-366.76055	.7500		77.129
L205	185.38468	23.3034	SiO2	77.193
	-1198.61550	A7500		74.782
L206	192.13950	11.8744	SiO2	73.634
	101.15610	27.6353		68.213
L207	-404.17514	7.0000	SiO2	61.022
	129.70591	24.1893		60.533
L208	-235.98146	7.0584	SiO2	58.732
	-203.88450	.7500		59.144
L209	-241.72595	7.0000	SiO2	60.201
	196.25453	33.3115		60.490
L210	-122.14995	7.0000	SiO2	65.017
	-454.65265	A 10.8840		66.412
L211	-263.01247	22.6024	SiO2	77.783
	-149.71102	1.6818		81.685
L212	-23862.31899	43.2680	SiO2	86.708
	-166.87793	.7500		104.023
L213	340.37670	44.9408	SiO2	106.012
	-355.50943	.7500		115.503
L214	160.11879	41.8646	SiO2	115.398
	4450.50491	.7500		102.982
L215	172.51429	14.8261	SiO2	100.763
	116.88490	35.9100		86.869
L216	-395.46894	7.0000	SiO2	74.187
	178.01469	28.0010		72.771
L217	-176.03301	7.0000	SiO2	66.083
	188.41213	36.7224		66.613
L218	-112.43820	7.0059	SiO2	66.293
	683.42330	17.1440		66.917
L219	-350.01763	19.1569	SiO2	80.240
	-194.58551	.7514		82.329
L220	-8249.50149	35.3656	SiO2	87.159
	-213.88820	.7500		99.995
L221	657.56358	31.3376	SiO2	103.494
	-428.74102	.0000		114.555
	infinity	2.8420		115.245
L222	stop	.0000		116.016
	820.30582	27.7457	SiO2	116.016
L223	-520.84842	18.4284		118.186
	330.19065	37.7586	SiO2	118.605
	-672.92481	23.8682		118.273
				117.550

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Table 2  
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L224	-233.67936	10.0000	SiO <sub>2</sub>	116.625
L225	-538.42627	10.4141	SiO <sub>2</sub>	117.109
	-340.26626	21.8583	SiO <sub>2</sub>	116.879
	-224.85666	.7500	SiO <sub>2</sub>	117.492
L226	146.87143	34.5675	SiO <sub>2</sub>	100.303
	436.70958	.7500	SiO <sub>2</sub>	97.643
L227	135.52861	29.8244	SiO <sub>2</sub>	86.056
	284.57463	18.9234	SiO <sub>2</sub>	79.427
L228	-7197.04545	11.8089	SiO <sub>2</sub>	72.964
	268.01973	.7500	SiO <sub>2</sub>	63.351
L229	100.56453	27.8623	SiO <sub>2</sub>	56.628
	43.02551	2.0994	SiO <sub>2</sub>	38.612
L230	42.30652	30.9541	SiO <sub>2</sub>	36.023
	262.65551	1.9528	SiO <sub>2</sub>	28.009
	infinity	12.0000		27.482
	infinity			13.602

Aspheric Constants:Coefficients of the aspheric surface  $n$ :[where  $n$  is 29]

$$\begin{aligned} EX &= -0.17337407 \cdot 10^3 \\ C_1 &= 0.15292522 \cdot 10^7 \\ C_2 &= 0.18756271 \cdot 10^{11} \\ C_3 &= -0.40702661 \cdot 10^{16} \\ C_4 &= 0.28176919 \cdot 10^{-19} \\ C_5 &= -0.36300252 \cdot 10^{-23} \\ C_6 &= 0.42405765 \cdot 10^{-47} \end{aligned}$$

Coefficients of the aspheric surface  $n$ :[where  $n$  is 27]

$$\begin{aligned} EX &= -0.38949981 \cdot 10^3 \\ C_1 &= 0.20355563 \cdot 10^7 \\ C_2 &= -0.22884234 \cdot 10^{11} \\ C_3 &= -0.23852614 \cdot 10^{18} \\ C_4 &= -0.19091022 \cdot 10^{-19} \\ C_5 &= 0.27737562 \cdot 10^{-23} \\ C_6 &= -0.29709625 \cdot 10^{-47} \end{aligned}$$

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Table 3  
page 1

m745a Lenses	Radii	Thicknesses	Glasses	1/2 x Lens Diameter
-----------------	-------	-------------	---------	---------------------

	infinity	17.8520		60.958
L301	-131.57692	7.0000	SiO2	61.490
	-195.66940	.7600		64.933
L302	-254.66368	8.4334	SiO2	65.844
	-201.64480	.7500		67.386
L303	-775.65764	14.0058	SiO2	69.629
	-220.44596	.7500		70.578
L304	569.58638	18.8958	SiO2	72.689
	-308.25184	.7600		72.876
L305	202.68033	20.7802	SiO2	71.232
	-1120.20883	A7600		70.282
L306	203.03395	12.1137	SiO2	65.974
	102.61512	26.3989		59.666
L307	-372.05336	7.0000	SiO2	59.203
	144.40889	23.3866		58.326
L308	-207.93626	7.0303	SiO2	58.790
	-184.65938	.7500		59.985
L309	-201.97720	7.0000	SiO2	60.229
	214.57715	33.1495		65.721
L310	-121.80702	7.0411	SiO2	67.235
	-398.26353	A9.7571		79.043
L311	-242.40314	22.4966	SiO2	81.995
	-146.76339	.7553		87.352
L312	-2729.19984	45.3237	SiO2	104.995
	-158.37001	.7762		107.211
L313	356.37642	52.1448	SiO2	118.570
	-341.95165	1.1921		118.519
L314	159.83842	44.6278	SiO2	105.627
	2234.73586	.7698		102.722
L315	172.14697	16.6360	SiO2	88.037
	119.63455	36.6804		75.665
L316	-392.62196	7.0000	SiO2	74.246
	171.18767	29.4986		67.272
L317	-178.75022	7.0000	SiO2	66.843
	186.50720	38.4360		67.938
L318	-113.94008	7.0213	SiO2	68.650
	893.30270	17.7406		82.870
L319	-327.77804	18.9809	SiO2	85.090
	-192.72640	.7513		89.918
L320	-3571.89972	34.3608	SiO2	103.882
	-209.35555	.7500		105.573
L321	676.38083	32.6220	SiO2	119.191
	-449.16650	.0000		119.960
	infinity	2.8420		120.991
	stop	.0000		120.991
L322	771.53843	30.6490	SiO2	123.568
	-525.59771	13.4504		124.006
L323	330.53202	40.0766	SiO2	123.477
	-712.47666	23.5787		122.707

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Table 3  
page 2

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L324	-250.00950	10.0000	SiO <sub>2</sub>	121.877
	-513.10270	14.8392		121.995
L325	-344.63359	20.3738	SiO <sub>2</sub>	121.081
	-239.53067	.7500		121.530
L326	146.13385	34.7977	SiO <sub>2</sub>	102.544
	399.32557	.7510		99.992
L327	132.97289	29.7786	SiO <sub>2</sub>	87.699
	294.53397	18.8859		82.024
L328	.3521.27938	A11.4951	SiO <sub>2</sub>	75.848
	287.11065	.7814		65.798
L329	103.24804	27.8602	SiO <sub>2</sub>	58.287
	41.64286	1.9089		36.734
L330	41.28081	31.0202	SiO <sub>2</sub>	36.281
	279.03201	1.9528		28.934
	infinity	12.0000		28.362
	infinity			13.603

Aspheric Constants:Coefficients of the aspheric surface n:

EX = -0.16784093 \* 10<sup>3</sup> [where n is 29]

C 1 = 0.49600479 \* 10<sup>-8</sup>

C 2 = 0.31354487 \* 10<sup>-11</sup>

C 3 = -0.65827200 \* 10<sup>-15</sup>

C 4 = 0.44673095 \* 10<sup>-19</sup>

C 5 = -0.73057048 \* 10<sup>-23</sup>

C 6 = 0.91524489 \* 10<sup>-27</sup>

Coefficients of the aspheric surface n:

[where n is 27]

EX = -0.22247325 \* 10<sup>1</sup>

C 1 = 0.24479896 \* 10<sup>-7</sup>

C 2 = -0.22713172 \* 10<sup>-11</sup>

C 3 = 0.36324126 \* 10<sup>-15</sup>

C 4 = -0.17823959 \* 10<sup>-19</sup>

C 5 = 0.26799048 \* 10<sup>-23</sup>

C 6 = -0.27403392 \* 10<sup>-27</sup>

Coefficients of the aspheric surface n:

EX = 0 [where n is 31]

C 1 = -0.45136584 \* 10<sup>-9</sup>

C 2 = 0.34745936 \* 10<sup>-13</sup>

C 3 = 0.11805250 \* 10<sup>-17</sup>

C 4 = -0.87762405 \* 10<sup>-21</sup>

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Table 4

page 1

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Lenses	Radii	Thicknesses	Glasses	1/2 x Lens Diameter
--------	-------	-------------	---------	---------------------

	infinity	11.4557		
L401	-273.19566	7.0000	SiO2	61.339
	-277.09708	.7000		62.263
L402	-861.38885	8.9922	SiO2	63.765
	-339.26281	.7000		64.989
L403	118124.1371911.2867		SiO2	65.826
	-365.70154	.7000		66.916
L404	685.10936	13.1661	SiO2	67.416
	-485.98278	.7000		67.995
L405	387.55973	17.2335	SiO2	68.012
	-473.09537 A	.7000		67.247
L406	268.03965	9.9216	SiO2	66.728
	149.12863	23.8122		62.508
L407	-184.82363	7.0000	SiO2	58.531
	176.80719	21.4194		58.029
L408	-186.59114	.70000	SiO2	57.646
	218.73570	29.5024		58.045
L409	-129.31068	7.0000	SiO2	63.566
	-531.44773 A	17.2306		65.030
L410	-307.52016	22.4527	SiO2	76.481
	-148.36184	.7000		65.643
L411	-1302.18676	41.0516	SiO2	88.946
	-162.48723	.7000		105.065
L412	621.16978	41.1387	SiO2	107.106
	-294.49119	.7000		118.007
L413	160.06951	49.7378	SiO2	118.347
	-2770.71439 A	.7000		109.803
L414	152.16529	16.7403	SiO2	107.961
	106.43163	39.9369		89.160
L415	-630.55958	7.0000	SiO2	76.189
	170.63853	31.4993		74.955
L416	-154.61084	7.0000	SiO2	68.381
	262.66931	36.2904		67.993
L417	-113.57141	8.4328	SiO2	69.679
	772.56149	21.7682		70.272
L418	-278.33295	16.4890	SiO2	85.377
	-198.24799	.8689		87.710
L419	-3464.64038	37.5900	SiO2	92.554
	-214.63481	1.1929		107.590
L420	2970.07848	32.3261	SiO2	111.045
	-350.93217	2.5303		122.434
L421	1499.34256	25.8265	SiO2	123.849
	-561.19644	.0000		127.128
	infinity	.7510		127.371
L422	stop	.0000		126.539
	821.09016	39.5191	SiO2	126.559
	-1995.20557	.7000		127.453
L423	337.02437	41.8147	SiO2	127.499
	-659.23025	25.0233		126.619
				125.851

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L424	-242.66564	7.0000	SiO <sub>2</sub>	124.960
	-891.19390	9.7905		126.057
L425	-492.17516	41.0678	SiO <sub>2</sub>	124.887
	-242.55195	.7000		125.845
L426	145.04614	37.2406	SiO <sub>2</sub>	104.033
	406.88892	.7008		101.079
L427	119.31280	31.5532	SiO <sub>2</sub>	85.742
	249.69473	15.2917		79.561
L428	1411.93157	7.8700	SiO <sub>2</sub>	74.994
	281.90273	.7011		66.830
L429	143.95136	55.0835	SiO <sub>2</sub>	61.517
	404.13980	15.0000		32.177
	infinity	.0001		13.603
	infinity			13.603

Aspheric Constants:

Coefficients of the aspheric surface n:

[where n is 27]

$$\begin{aligned} EX &= 0,45321787 \cdot 10^2 \\ C 1 &= 0,12027601 \cdot 10^7 \\ C 2 &= -0,16206398 \cdot 10^{11} \\ C 3 &= -0,41686011 \cdot 10^{15} \\ C 4 &= 0,38440137 \cdot 10^{18} \\ C 5 &= -0,15095918 \cdot 10^{22} \\ C 6 &= -0,84812581 \cdot 10^{26} \end{aligned}$$

Coefficients of the aspheric surface n:

[where n is 29]

$$\begin{aligned} EX &= 0 \\ C 1 &= -0,97452539 \cdot 10^{-7} \\ C 2 &= 0,32591079 \cdot 10^{-11} \\ C 3 &= 0,97426255 \cdot 10^{-16} \\ C 4 &= -0,846124 \cdot 10^{-20} \\ C 5 &= -0,12332031 \cdot 10^{-23} \\ C 6 &= 0,14443713 \cdot 10^{-27} \end{aligned}$$

Coefficients of the aspheric surface n:

[where n is 33]

$$\begin{aligned} EX &= 0 \\ C 1 &= 0,63144137 \cdot 10^{-2} \\ C 2 &= 0,21837618 \cdot 10^{-12} \\ C 3 &= 0,22801998 \cdot 10^{-18} \\ C 4 &= -0,87807963 \cdot 10^{-21} \\ C 5 &= 0,42592446 \cdot 10^{-25} \\ C 6 &= -0,85709164 \cdot 10^{-30} \end{aligned}$$

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Table 5  
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Lenses	Radii	Thicknesses	Glasses.	$\frac{1}{4} \times$ Lens Diameter
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L501	infinity	9.9853		
	-265.92659	6.0000	SIO2	61.549
	857.92226	5.9813		62.237
L502	-2654.69270	14.4343	SIO2	65.916
	-244.65690	.7500		65.990
L503	1038.40194	15.9955	SIO2	68.482
	-333.95446	.7500		71.883
L504	359.47552	18.5128	SIO2	72.680
	-532.67816	.7500		74.430
L505	213.38035	21.4562	SIO2	74.416
	-1441.22634	A7500		72.985
L506	281.90156	6.5306	SIO2	72.045
	115.92184	28.4856		67.809
L507	-267.21040	6.0000	SIO2	62.818
	175.09702	23.2443		62.411
L508	-213.08557	6.0000	SIO2	61.923
	199.61141	30.8791		62.365
L509	-158.73046	6.0337	SIO2	68.251
	-1108.92217	A10.9048		69.962
L510	-314.37706	20.6413	SIO2	81.119
	-169.59197	.8014		84.163
L511	-3239.97175	43.6396	SIO2	88.902
	-168.44726	.7500		105.289
L512	495.41910	48.8975	SIO2	108.724
	-288.85737	.7500		123.274
L513	153.24868	48.7613	SIO2	123.687
	820.32139	A.7500		113.393
L514	163.02502	15.7110	SIO2	111.134
	124.97510	44.2664		96.188
L515	-422.99493	6.0000	SIO2	84.961
	184.60620	31.4985		83.633
L516	-241.93022	6.0000	SIO2	78.498
	168.30899	51.3978		76.180
L517	-117.43130	6.5332	SIO2	77.396
	2476.47953	21.4666		78.345
L518	-311.36041	15.2223	SIO2	98.469
	-221.58556	.7500		101.209
L519	-934.37047	37.6761	SIO2	105.324
	-216.75809	.7500		122.239
L520	3623.94786	39.5266	SIO2	125.425
	-370.69232	1.1289		146.583
L521	1209.82944	39.1543	SIO2	148.219
	-613.71745	.0000		157.194
	infinity	.7500		157.954
L522	stop	.0000		158.061
	709.88915	36.2662	SIO2	158.061
L523	-1035.75796	.7500		160.170
	313.44889	58.8000	SIO2	160.137
	-1046.56219	28.7484		155.263
				153.730

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L524	-328.67790	15.0000	SiO <sub>2</sub>	152.447
L525	-1283.32936	14.7084	SiO <sub>2</sub>	148.826
	-540.24577	23.9839	SiO <sub>2</sub>	148.336
	-305.19883	.7510		148.189
L526	152.28321	42.3546	SiO <sub>2</sub>	114.055
	384.50964	.7631		109.924
L527	124.66784	31.8554	SiO <sub>2</sub>	91.106
	279.80513	16.6796		86.038
L528	-28987.53974	7.4387	SiO <sub>2</sub>	82.126
	316.02224	.8631		72.044
L529	180.51161	54.1269	SiO <sub>2</sub>	67.036
	1341.25511	15.0000		37.374
	infinity.	.0001		13.804
	infinity.			13.804

Aspheric Constants:Coefficients of the aspheric surface n:

$$EX = -0.27012883 \cdot 10^3 \quad [\text{where } n \text{ is 29}]$$

$$C_1 = -0.48014089 \cdot 10^7$$

$$C_2 = 0.30075830 \cdot 10^{11}$$

$$C_3 = 0.34922943 \cdot 10^{-16}$$

$$C_4 = 0.26946301 \cdot 10^{-19}$$

$$C_5 = -0.58250631 \cdot 10^{-22}$$

$$C_6 = 0.68991391 \cdot 10^{-27}$$

Coefficients of the aspheric surface n:

$$EX = 0.41249481 \cdot 10^1 \quad [\text{where } n \text{ is 27}]$$

$$C_1 = -0.38239182 \cdot 10^{-6}$$

$$C_2 = -0.14976009 \cdot 10^{-11}$$

$$C_3 = -0.25206193 \cdot 10^{-18}$$

$$C_4 = -0.78282128 \cdot 10^{-20}$$

$$C_5 = 0.13017800 \cdot 10^{-21}$$

$$C_6 = -0.14205614 \cdot 10^{-27}$$

Coefficients of the aspheric surface n:

$$EX = 0.26320110 \cdot 10^1 \quad [\text{where } n \text{ is 33}]$$

$$C_1 = 0.27448935 \cdot 10^{-8}$$

$$C_2 = -0.18100074 \cdot 10^{-12}$$

$$C_3 = 0.58695756 \cdot 10^{-17}$$

$$C_4 = -0.58955753 \cdot 10^{-21}$$

$$C_5 = 0.15526308 \cdot 10^{-22}$$

$$C_6 = -0.25708759 \cdot 10^{-30}$$

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Coefficients of the aspheric surface n:

$EX = -0.96865859 \cdot 10^5$  [where n is 31]  
C 1 = -0.42411179  $\cdot 10^{-8}$   
C 2 = 0.12306058  $\cdot 10^{-12}$   
C 3 = 0.69229786  $\cdot 10^{-17}$   
C 4 = 0.80135737  $\cdot 10^{-20}$   
C 5 = -0.14022540  $\cdot 10^{-23}$   
C 6 = 0.79827308  $\cdot 10^{-26}$

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Table 6

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Lenses	Radius	Thicknesses	Glasses	1/2 x Lens Diameter
	infinity	5.9005	N2	32.429
L601	-125.95821	3.6410	CAF2	32.780
	243.24465	5.2309	He	35.323
L602	2472.77263	9.2265	CAF2	36.826
	-132.46523	.3958	He	37.854
L603	544.60759	8.6087	CAF2	40.080
	-188.98512	.6007	He	40.516
L604	180.26444	10.3984	CAF2	41.764
	-394.70139	.4244	He	41.743
L605	101.06312	12.8236	CAF2	40.955
	-691.58627	A .5111	He	40.455
L606	135.75849	3.1245	CAF2	37.553
	57.03094	16.2396	He	34.284
L607	-268.26919	5.9149	CAF2	33.871
	116.53569	10.9654	He	33.188
L608	-142.54676	3.2195	SiO2	33.372
	100.09171	16.1921	He	35.360
L609	-83.03185	3.2311	SiO2	36.264
	-453.73264	A .5.1711	He	41.718
L610	-167.92924	12.0560	CAF2	43.453
	-93.29791	.4204	He	47.010
L611	-1270.46545	24.2891	CAF2	56.224
	-90.89540	1.1471	He	58.224
L612	256.81271	25.6379	CAF2	65.498
	-171.23587	.3619	He	66.755
L613	82.41217	26.8409	CAF2	61.351
	529.17259	A .5132	He	60.098
L614	81.87977	8.2278	CAF2	50.462
	64.06536	22.9801	He	44.346
L615	-259.83061	3.3437	SiO2	43.473
	124.29419	13.5357	He	40.256
L616	-197.28109	3.0000	SiO2	39.809
	87.83707	24.6613	He	39.571
L617	-64.97274	4.6170	SiO2	40.050
	1947.71286	9.3909	He	49.830
L618	-182.16003	7.8052	CAF2	51.480
	-118.82950	.3753	He	53.449
L619	-633.93522	19.7976	CAF2	63.119
	-115.14087	.3706	He	64.793
L620	2647.04517	19.8039	CAF2	75.458
	-197.41705	2.7167	He	76.413
L621	668.45083	30.1057	CAF2	81.369
	-322.45899	.0001	He	82.659
	infinity	.3948	He	82.583
	stop	.0000		82.583
L622	395.84774	16.8754	CAF2	83.488
	-635.79877	.3800	He	83.449
L623	165.28880	28.1341	CAF2	80.781
	-698.21798	15.6657	He	80.133

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L624	-175.54365	7.9803	SiO <sub>2</sub>	79.485
L625	-571.27581	9.7972	He	78.592
	-265.73712	11.6714	CAF2	78.015
L626	-156.05301	.3500	He	78.036
	79.45912	22.6348	CAF2	60.151
L627	199.26460	.3500	He	57.925
	67.01872	15.8836	CAF2	48.063
L628	140.01631	8.6050	He	45.305
	2265.71693	A4.0939	SiO <sub>2</sub>	43.177
L629	167.06050	2.0915	He	38.352
	102.24013	24.5664	CAF2	34.878
	662.00758	9.4740	N2	22.044
UNENDL	.0001	N2		7.166
UNENDL				7.166

Aspheric Constants:Coefficients of the aspheric surface n:[where n is 29]

$$\begin{aligned} EX &= -0.7980946 \cdot 10^2 \\ C_1 &= -0.21353640 \cdot 10^{-6} \\ C_2 &= 0.56257 \cdot 10^{-10} \\ C_3 &= -0.39122939 \cdot 10^{-14} \\ C_4 &= -0.24089766 \cdot 10^{-18} \\ C_5 &= 0.30268982 \cdot 10^{-22} \\ C_6 &= 0.1437923 \cdot 10^{-25} \end{aligned}$$

Coefficients of the aspheric surface n:[where n is 27]

$$\begin{aligned} EX &= 0.1660595 \cdot 10^1 \\ C_1 &= -0.12449719 \cdot 10^{-7} \\ C_2 &= -0.39585 \cdot 10^{-10} \\ C_3 &= -0.10241741 \cdot 10^{-14} \\ C_4 &= -0.19831485 \cdot 10^{-17} \\ C_5 &= 0.11604236 \cdot 10^{-20} \\ C_6 &= -0.4669584 \cdot 10^{-24} \end{aligned}$$

Coefficients of the aspheric surface n:[where n is 33]

$$\begin{aligned} EX &= 0.1614147 \cdot 10^0 \\ C_1 &= 0.14130608 \cdot 10^{-7} \\ C_2 &= -0.9747553 \cdot 10^{-11} \\ C_3 &= 0.20478684 \cdot 10^{-15} \\ C_4 &= -0.17732262 \cdot 10^{-19} \\ C_5 &= 0.29715991 \cdot 10^{-22} \\ C_6 &= -0.19032581 \cdot 10^{-26} \end{aligned}$$

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Coefficients of the aspheric surface  $n$ : $EX = 0$ [where  $n$  is 31]

$$C_1 = -0.18139679 \cdot 10^{-7}$$

$$C_2 = 0.26109059 \cdot 10^{-11}$$

$$C_3 = 0.23340548 \cdot 10^{-14}$$

$$C_4 = 0.29943791 \cdot 10^{-17}$$

$$C_5 = -0.13596787 \cdot 10^{-20}$$

$$C_6 = 0.21788235 \cdot 10^{-24}$$

Abstract of the Disclosure

The invention relates to a projection lens comprising a lens assembly that has at least one first narrowing of the group of light beams. A lens with a non-spherical surface is located in front of and/or behind the first narrowing.

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Schuster  
Substitute Specification

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